











ADS1259-Q1

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ADS1259-Q1 Automotive, 14.4-kSPS, 24-Bit Analog-to-Digital Converter With Integrated Low-Drift Reference

Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the Following Results:
 - Temperature Grade 1: –40°C to 125°C
 - HBM ESD Classification 2
 - CDM ESD Classification C4B
- Programmable Data Rates: 10 SPS to 14.4 kSPS
- Single-Cycle Settling Digital Filter
- High Performance:
 - 21.3 ENOB at 1.2 kSPS
 - INL: 3 ppm
 - Offset Drift: 0.05 µV/°C Gain Drift: 0.5 ppm/°C
- Internal Reference: 2.5 V, 10 ppm/°C Drift
- Internal 2% Accurate Oscillator
- Input Signal Out-of-Range Detection
- Optional Checksum and Redundant Data-Read Capability to Augment Data Integrity
- SPI™-Compatible Interface, Mode 1
- Analog Supply: 5 V or ±2.5 V
- Digital Supply: 2.7 V to 5 V

Applications

- Automotive Power Train
- **Electrical Vehicles**

3 Description

The ADS1259-Q1 is a precision, low-drift, 24-bit, analog-to-digital converter (ADC). The device can perform conversions at data rates up to 14.4 kSPS with high resolution and is therefore ideally suited to measure rapidly changing signals that have a wide dynamic range. An integrated low-noise, low-drift 2.5-V reference eliminates the need for an external voltage reference, thus reducing system cost and component count.

The converter uses a fourth-order, inherently stable, delta-sigma ($\Delta\Sigma$) modulator that provides outstanding noise performance and linearity. The device can use the integrated oscillator, an external crystal, or an external clock as the ADC clock source.

A fast-responding input overrange detector flags the conversion data if an input overrange event occurs. To augment data integrity in noisy automotive environments the ADS1259-Q1 offers an optional checksum byte and a redundant conversion dataread capability.

The ADS1259-Q1 consumes 13 mW during operation and less than 25 µW when powered down. TI offers the ADS1259-Q1 device in a TSSOP-20 package with full specification from -40°C to 125°C.

Device Information

ORDER NUMBER	PACKAGE	BODY SIZE
ADS1259QPWRQ1	TSSOP (20)	6.5 mm × 4.4 mm

ADS1259-Q1 Simplified Block Diagram

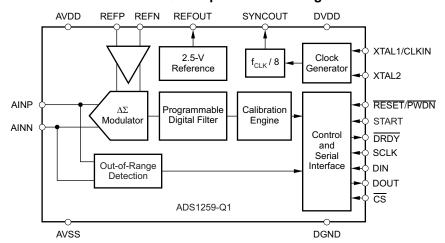




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4 Revision History

DATE	REVISION	NOTES
March 2014	*	Initial release

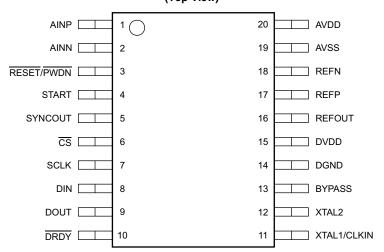
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5 Terminal Configuration and Functions

20-Terminal TSSOP PW Package (Top View)



Terminal Functions

т	RMINAL		Terminal Functions
	1	TYPE	DESCRIPTION
NO.	NAME		
1	AINP	Analog input	Positive analog input
2	AINN	Analog input	Negative analog input
3	RESET/PWDN	Digital input	Reset or power down; reset is active-low; hold low for power down.
4	START	Digital input	Start conversions, active-high
5	SYNCOUT	Digital output	Sync clock output (f _(CLK) / 8)
6	CS	Digital input	SPI chip-select, active-low
7	SCLK	Digital input	SPI clock input
8	8 DIN		SPI data input
9 DOUT Digital output SPI data output		SPI data output	
10	DRDY	Digital output	Data-ready output, active-low
11	XTAL1/CLKIN	Digital input	Internal oscillator: DGND External clock: clock input Crystal oscillator: external crystal1
12	XTAL2	Digital	External crystal2, otherwise no connection
13	BYPASS	Analog	Core voltage bypass. Connect a 1-µF capacitor to DGND.
14	DGND	Digital	Digital ground
15	DVDD	Digital	Digital power supply
16 REFOUT Analog output Positive internal reference output. Connect a 1-µF cap		Positive internal reference output. Connect a 1-µF capacitor, C _{REFOUT} , to AVSS.	
17 REFP Analog input		Analog input	Positive reference input. Connect a 1-µF capacitor, C _{REFIN} , to REFN. (1)
18	REFN	Analog input	Negative reference input ⁽¹⁾
19	AVSS	Analog	Negative analog power supply and negative internal reference output
20	AVDD	Analog	Positive analog power supply

⁽¹⁾ Leave unused reference inputs unconnected or tie to AVDD.



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating ambient temperature range (unless otherwise noted)

		MIN	MAX	UNIT
AVDD to AVSS		-0.3	7	V
AVSS to DGND		-2.8	0.3	V
DVDD to DGND		-0.3	7	V
Analog input voltage	AINN, AINP, REFN, REFP	AVSS - 0.3	AVDD + 0.3	V
Digital input voltage	CS, DIN, RESET/PDWN, SCLK, START, XTAL1/CLKIN	DGND - 0.3	DVDD + 0.3	V
Input current, continuous	Any terminal except supply terminals	-10	10	mA
Operating junction temperature	e, T _J	-40	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Handling Ratings

		MIN	MAX	UNIT
T _{stg}	Storage temperature range	-60	150	°C
v (1)	Human-body model (HBM) ESD stress voltage ⁽²⁾	-2	2	kV
V _(ESD) (1)	Charged-device model (CDM) ESD stress voltage (2)	-1	1	kV

Electrostatic discharge (ESD) to measure device sensitivity or immunity to damage caused by assembly-line electrostatic discharges into the device.

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⁽²⁾ Meets or exceeds the passing level per AEC-Q100.



6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
POWER SUPPLY				-1	
Analog newer august.	AVDD to AVSS	4.75	5.0	5.25	V
Analog power supply	AVSS to DGND	-2.6	-2.5	0	V
Digital power supply	DVDD to DGND	2.7	3.3	5.25	V
ANALOG INPUTS					
Absolute input voltage	AINP or AINN	AVSS - 0.1		AVDD + 0.1	V
Differential input voltage ⁽¹⁾ $V_{(IN)} = (V_{(AINP)} - V_{(AINN)})$		-V _{ref}		V_{ref}	V
VOLTAGE REFERENCE INPUTS					
Reference input voltage	$V_{ref} = (V_{(REFP)} - V_{(REFN)})$	0.5	2.5	AVDD – AVSS + 0.2	V
Absolute negative reference voltage	REFN	AVSS - 0.1	AVSS	REFP - 0.5	V
Absolute positive reference voltage	REFP	REFN + 0.5	AVSS + 2.5	AVDD + 0.1	V
EXTERNAL CLOCK SOURCES (f _{(CL}	.к))			•	
Crystal oscillator	Frequency	2	7.3728	8	MHz
Establish de la	Frequency	0.1	7.3728	8	MHz
External clock	Duty cycle	40%		60%	
DIGITAL INPUTS					
High-level input voltage, V _{IH}		0.8 DVDD		DVDD	V
Low-level input voltage, V _{IL}		DGND		0.2 DVDD	V
TEMPERATURE RANGE	1			1	
Operating ambient temperature, T _A		-40		125	°C

⁽¹⁾ Excluding the effects of offset and gain error.

6.4 Thermal Information

	THERMAL METRIC ⁽¹⁾	PW (20 TERMINALS)	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86.9	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	21	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	39.1	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.8	°C/W
ΨЈВ	Junction-to-board characterization parameter	38.4	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

TEXAS INSTRUMENTS

6.5 Electrical Characteristics

Minimum and maximum specifications are at $T_A = -40^{\circ}\text{C}$ to 125°C. Typical specifications are at $T_A = 25^{\circ}\text{C}$, AVDD = 2.5 V, AVSS = -2.5 V, DVDD = 3.3 V, external $f_{(CLK)} = 7.3728$ MHz, external $V_{ref} = 2.5$ V, and $f_{(DATA)} = 60$ SPS (unless otherwise noted)

PARAMETER	MHz, external $V_{ref} = 2.5 \text{ V}$, and $f_{(DATA)} = 60 \text{ TEST CONDITIONS}$	MIN	TYP	MAX	UNIT	
ANALOG INPUTS				<u> </u>		
Differential input impedance			120		kΩ	
Common-mode input impedance			500		kΩ	
SYSTEM PERFORMANCE	+					
Resolution (no missing codes)		24			Bits	
Data rate, f _(DATA)		10		14,400	SPS	
Noise (input referred)	Shorted inputs, See SBAS424 for more information.		0.7		μV_{RMS}	
Integral nonlinearity, INL	Best-fit method	-10	±3	10	ppm	
Offset voltage (input referred)		-250	±40	250	μV	
Offset voltage after calibration ⁽¹⁾			±1		μV	
Offset drift	T _A = -40°C to 125°C		0.05	0.25	μV/°C	
Gain error ⁽²⁾		-0.5%	±0.05%	0.5%		
Gain error after calibration ⁽¹⁾			±0.0002%			
Gain drift	T _A = -40°C to 125°C		0.5	2.5	ppm/°C	
Normal-mode rejection ratio, NMRR			See SBAS424.			
Common-mode rejection ratio, CMRR	60 Hz, ac ⁽³⁾	100	120		dB	
AVDD, AVSS power-supply rejection ratio, PSRR	60 Hz, ac ⁽³⁾	85	95		dB	
DVDD power supply-rejection ratio, PSRR	60 Hz, ac ⁽³⁾	85	110		dB	
OUT-OF-RANGE DETECTION	+					
Threshold level	AVSS + 150 mV ≤ V _(AINP) , V _(AINN) ≤ AVDD − 150 mV		±105		%FSR	
Threshold level accuracy	AVSS + 150 mV ≤ V _(AINP) , V _(AINN) ≤ AVDD − 150 mV		±0.5		%FSR	
VOLTAGE REFERENCE INPUTS						
Average reference input current	AVSS ≤ V _(REFP) , V _(REFN) ≤ AVDD		350		nA	
Average reference input current drift			0.2		nA/°C	
INTERNAL VOLTAGE REFERENCE						
Reference output voltage	$V_{(REFOUT)} = (REFOUT - AVSS)$		2.5		V	
Accuracy	T _A = 25°C	-0.4%		0.4%		
Temperature drift	T _A = -40°C to 125°C		10	40	ppm/°C	
Drive current (sink and source)		-10		10	mA	
Load regulation			10		μV/mA	
Turn-on settling time	$\pm 0.001\%$ settling, $C_{REFIN} = 1 \mu F$, $C_{REFOUT} = 1 \mu F$		1		S	
Long-term stability	0 to 1000 hours		70		ppm	
Thermal hysteresis			30		ppm	
CLOCK SOURCE (f _(CLK))						
Internal oscillator frequency			7.3728		MHz	
Internal oscillator accuracy		-2%	±0.2%	2%		
External crystal oscillator start-up time ⁽⁴⁾	18-pF load capacitors		20		ms	
DIGITAL INPUTS AND OUTPUTS (DVDD = 2.7 V	to 5.25 V)					
·	I _{OH} = 1 mA	0.8 DVDD				
High-level output voltage, V _{OH}	I _{OH} = 8 mA		0.75 DVDD		V	
	I _{OL} = 1 mA			0.2 DVDD		
Low-level output voltage, V_{OL}	I _{OL} = 8 mA		0.2 DVDD		V	
Input hysteresis	32		0.1		V	
					•	

¹⁾ Calibration accuracy is on the level of noise (signal and ADC), reduced by the effect of 16-reading averaging.

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⁽²⁾ Excludes internal reference error.

⁽³⁾ f_(DATA) = 14.4 kSPS. Placing a notch of the digital filter at 60 Hz (setting f_(DATA) = 10 SPS or 60 SPS) further improves the common-mode rejection and power-supply rejection of this input frequency.

⁽⁴⁾ External crystal start-up time can vary with crystal manufacturer and over temperature.



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Electrical Characteristics (continued)

Minimum and maximum specifications are at $T_A = -40^{\circ}\text{C}$ to 125°C. Typical specifications are at $T_A = 25^{\circ}\text{C}$, AVDD = 2.5 V, AVSS = -2.5 V, DVDD = 3.3 V, external $f_{(CLK)} = 7.3728$ MHz, external $V_{ref} = 2.5$ V, and $f_{(DATA)} = 60$ SPS (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
POWER SUPPLY				
	Operating (internal reference enabled)		2.3 5	mA
Absolute analog supply current (AVDD, AVSS)	Standby mode (internal reference enabled)		200	
	Standby mode (internal reference disabled)		1	μA
	Power-down mode		1	
	Operating (internal oscillator ⁽⁵⁾)		500 700	
Digital supply current (DVDD)	Standby mode (internal oscillator)		160 300	μА
	Power-down mode (external CLKIN, SCLK stopped, digital inputs maintained at V _{IH} or V _{IL} voltage levels)		1 10	
	Operating (internal reference enabled, internal oscillator)		13 28	
Power dissipation	Standby mode (internal reference enabled, internal oscillator)		1.5	mW
	Standby mode (internal reference disabled, internal oscillator)		0.5	
	Power-down mode		10	μW

(5) Internal oscillator current: 40 μA (typ.)

7 Residue

See SBAS424 for any information on the ADS1259-Q1 device that is not covered in the foregoing sections.

TEXAS INSTRUMENTS

8 Device Documentation and Support

8.1 Trademarks

SPI is a trademark of Motorola.

All other trademarks are the property of their respective owners.

8.2 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

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9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
ADS1259QPWRQ1	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AD1259Q1
ADS1259QPWRQ1.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AD1259Q1

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF ADS1259-Q1:

Catalog: ADS1259

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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NOTE: Qualified Version Definitions:

 $_{\bullet}$ Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS1259QPWRQ1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Ì	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	ADS1259QPWRQ1	TSSOP	PW	20	2000	353.0	353.0	32.0	



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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